### VS-30CTQ0.0S-M3, VS-30CTQ0.0-1-M3 Series

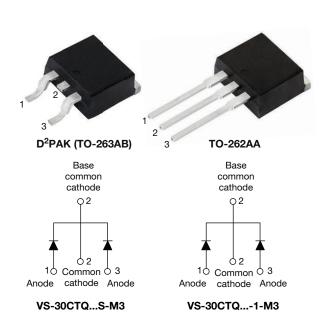
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COMPLIANT

**HALOGEN** 

## High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 2 x 15 A					
$V_{R}$	50 V, 60 V				
V <sub>F</sub> at I <sub>F</sub>	0.56 V				
I <sub>RM</sub> typ.	45 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	13 mJ				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	30	А			
V <sub>RRM</sub>		50/60	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1000	A			
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.56	V			
T <sub>J</sub>	Range	-55 to +150	°C			

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-30CTQ050S-M3 VS-30CTQ060S-M3 VS-30CTQ060-1-M3 UNITS							
Maximum DC reverse voltage	$V_R$	50	60	V			
Maximum working peak reverse voltage	$V_{RWM}$	50	00	V			

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	PARAMETER		TEST CONDITIONS		VALUES	UNITS		
Maximum average	per device		50 % duty cycle at T <sub>C</sub> = 105 °C, rectangular waveform		30			
forward current See fig. 5	per leg	I <sub>F(AV)</sub>			15	A		
Maximum peak one cycle	non-repetitive		5 μs sine or 3 μs rect. pulse Following any rated load		1000	_ ^		
surge current per leg See fig. 7		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	260			
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	$T_J = 25$ °C, $I_{AS} = 1.50$ A, L = 11.5 mH		13	mJ		
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.50	А		

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		15 A	T <sub>.1</sub> = 25 °C	0.62	V		
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	30 A	11 = 23 0	0.82			
See fig. 1	V FM (1)	15 A	T <sub>J</sub> = 125 °C	0.56			
		30 A	1j = 125 C	0.71			
Maximum various legicage accurrent new leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.80	· mA		
Maximum reverse leakage current per leg		T <sub>J</sub> = 125 °C		160			
Typical reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	45	mA		
Threshold voltage	V <sub>F(TO)</sub>	T T mayimum		0.39	V		
Forward slope resistance	r <sub>t</sub>	ıj = ıj maxımum	$T_J = T_J$ maximum		mΩ		
Maximum junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		720	pF		
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 r	8.0	nΗ			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width  $<300~\mu s,$  duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	Э	T <sub>J</sub> , T <sub>Stg</sub>		-55 to 150	°C		
Maximum thermal resistance, junction to case per leg		D	DC operation	3.25	°C/W		
Maximum thermal resistance, junction to case per package		- R <sub>thJC</sub>	DC operation	1.63	C/VV		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50			
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque maximum				12 (10)	(lbf · in)		
Marking device			Case style D <sup>2</sup> PAK (TO-263AB)		Q050S Q060S		
			Case style TO-262AA	30CTC			

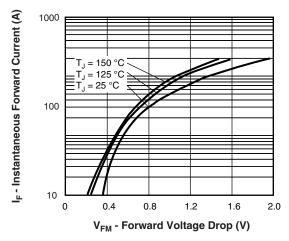
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1000 100 T<sub>1</sub> = 150 °C IR -Reverse Current (mA) = 125 °C 10 = 100 °C = 75 °C 0.1 = 50 °C = 25 °C 0.01 0.001 10 60 V<sub>R</sub> - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

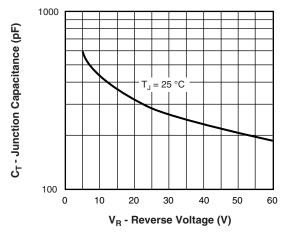


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

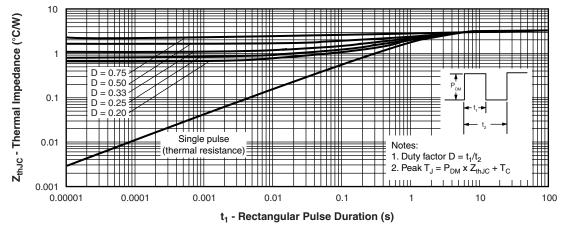


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics (Per Leg)

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Allowable Case Temperature (°C)

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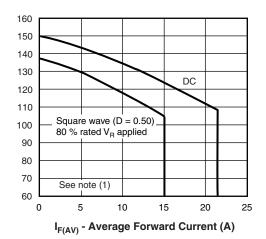


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

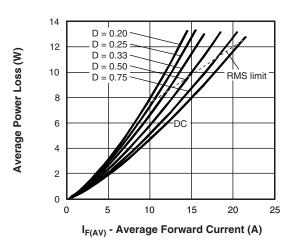


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

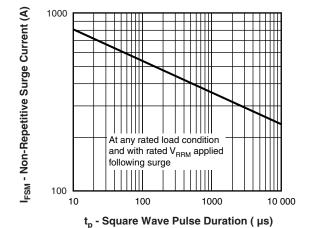


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

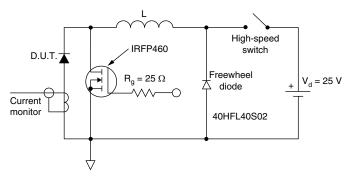


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = 10 \ \text{V}. \end{array}$ 

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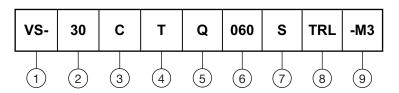


## VS-30CTQ0.0S-M3, VS-30CTQ0.0-1-M3 Series

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#### **ORDERING INFORMATION TABLE**

#### **Device code**



1 - Vishay Semiconductors product

2 - Current rating (30 A)

Circuit configuration: C = common cathode

**4** - T = TO-220

5 - Schottky "Q" series

6 - Voltage ratings - 050 = 50 V 060 = 60 V

7 - •  $S = D^2PAK (TO-263AB)$ 

• -1 = TO-262AA

8 - • None = tube

• TRL = tape and reel (left oriented - for D<sup>2</sup>PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D<sup>2</sup>PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-30CTQ050S-M3	50	Antistatic plastic tubes					
VS-30CTQ050STRR-M3	800	13" diameter plastic tape and reel					
VS-30CTQ050STRL-M3	800	13" diameter plastic tape and reel					
VS-30CTQ050-1-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS					
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164			
Differsions	TO-262AA	www.vishay.com/doc?96165			
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444			
Fait marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			

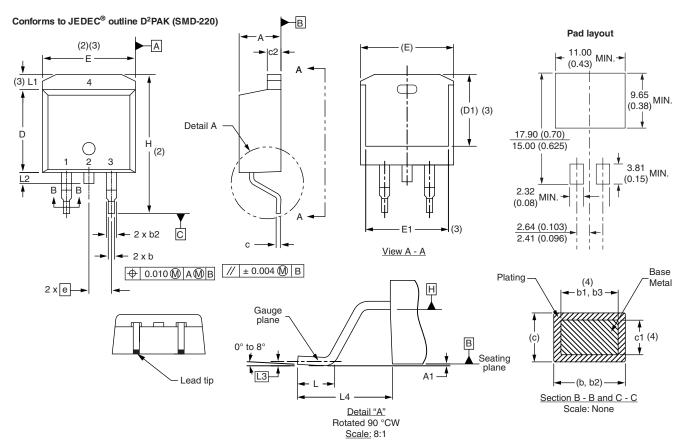
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### D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	ETERS INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

- $^{(1)}$  Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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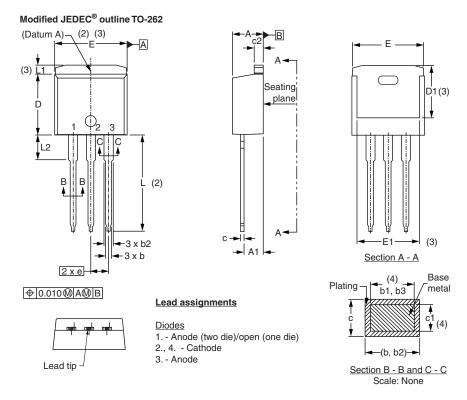




## Vishay Semiconductors

### **TO-262**

#### **DIMENSIONS** in millimeters and inches



CVMPOL	MILLIMETERS		INC	NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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